

TS3V555

3V LOW POWER SINGLE TIMERS

- DEDICATED TO 3.3V OR BATTERY SUPPLY (Specified at 3V and 5V)
- VERY LOW POWER CONSUMPTION : 90µA typ at V_{CC} = 3V
- WIDE SINGLE SUPPLY RANGE : +2.7V to +16V
- HIGH OUTPUT CURRENT CAPABILITY
- SUPPLY CURRENT SPIKES REDUCED DURING OUTPUT TRANSITIONS
- HIGH INPUT IMPEDANCE : 10¹²Ω
- PIN-TO-PIN AND FUNCTIONALLY COMPATIBLE WITH BIPOLAR NE555 AND CMOS TS555
- OUTPUT COMPATIBLE WITH TTL,CMOS AND LOGIC MOS

DESCRIPTION

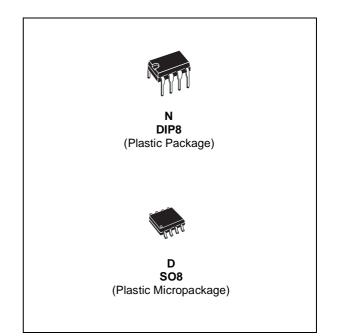
The TS3V555 with its low consumption (90µA at V_{CC} = 3V) is a single CMOS timer dedicated to 3.3V or battery supply (specified at 3V and 5V) offering also a high frequency ($f_{(max)}$ 2MHz at V_{CC} = 3V and 2.7MHz at V_{CC} = 5V). Thus, either in monosatble or astable mode, timing remains verv accurate.

Timing capacitors can also be minimized due to high input impedance $(10^{12}\Omega)$.

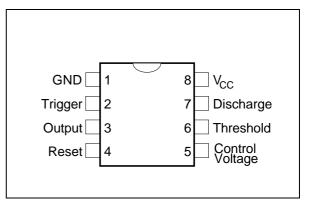
ORDER CODE

Part Number	Temperature Range	Pac	kage
Fait Nulliber	Temperature Range	N	D
TS3V555I	-40, +125°C	•	•

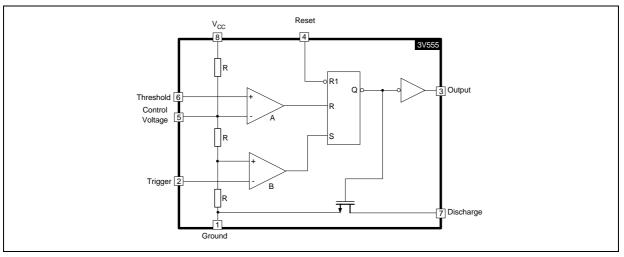
 $\begin{array}{l} \textbf{N} = \text{Dual in Line Package (DIP)} \\ \textbf{D} = \text{Small Outline Package (SO) - also available in Tape & Reel (DT)} \\ \textbf{P} = \text{Thin Shrink Small Outline Package (TSSOP) - only available} \\ \text{in Tape & Reel (PT)} \end{array}$



PIN CONNECTIONS (top view)



BLOCK DIAGRAM



RESET	TRIGGER	THRESHOLD	OUTPUT
Low	х	х	Low
High	Low	х	High
High	High	High	Low
High	High	Low	Previous State

<----> Irrelevant Х

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	+18	V
Тj	Junction Temperature	+150	°C

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
T _{oper}	Operating Free Air Temperature Range TS3V555I, AI	-40 to 125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	+2.7 to +16	V

ELECTRICAL CHARACTERISTICS

$V_{CC} = +3V$, T_{amb}	= +25°C, Reset to	V _{CC} (unless	otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
Icc	Supply Current (no load, High and Low States) T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}		90	230 230	μA
V _{CL}	Control Voltage Level $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	1.8 1.7	2	2.2 2.3	V
V _{dis}	Discharge Stauration Voltage ($I_{dis} = 1mA$) $T_{amb} = +25$ °C $T_{min.} \le T_{amb} \le T_{max.}$		0.05	0.2 0.25	V
V _{OL}	Low Level Output Voltage ($I_{sink} = 1mA$) $T_{amb} = +25$ °C $T_{min.} \le T_{amb} \le T_{max.}$		0.1	0.3 0.35	V
V _{OH}	High Level Output Voltage (I _{source} = -0.3mA) T_{amb} = +25°C $T_{min.} \le T_{amb} \le T_{max.}$	2.5 2.5	2.9		V
V _{trig}	Trigger Voltage T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}	0.9 0.8	1	1.1 1.2	V
l _{trig}	Trigger Current		10		pА
I _{TH}	Threshold Current		10		pА
V _{reset}	Reset Voltage T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}	0.4 0.3	1.1	1.5 2.0	V
I _{reset}	Reset Current		10		pА
I _{dis}	Discharge Pin Leakage Current		1	100	nA

DYNAMIC

Symbol	Parameter	Min.	Тур.	Max.	Unit
	Timing Accuracy (Monostable) - note ¹⁾ R = $10k\Omega$, C = 0.1μ F		1		%
	Timing Shift with Supply Voltage Variations (Monostable $R = 10k\Omega$, $C = 0.1\mu$ F,V _{CC} = +3V ±0.3V - see note 1		0.5		%/V
	Timing Shift with Temperature - see note 1 $T_{min.} \le T_{amb} \le T_{max}.5$		75		ppm/°C
f _{max}	Maximum Astable Frequency - note ²⁾ $R_A = 470\Omega$, $R_B = 200\Omega$, $C = 200pF$		2		MHz
	Astable Frequency Accuracy - see note 2 $R_A = R_B = 1k\Omega$ to 100k Ω , C = 0.1µF		5		%
	Timing Shift with Supply Voltage Variations (Astable mode) - see note 2 $R_A = R_B = 1k\Omega$ to $100k\Omega$, C = 0.1μ F, V _{CC} = +3 to +5V		0.5		%/V
tr	Output Rise Time (C _{load} = 10pF)		25		ns
tf	Output Fall Time ₍ C _{load} = 10pF)		20	-	ns
tpd	Trigger Propagation Delay)		100		ns
trpw	Minimum Reset Pulse Width (V _{trig} = +3V)		350		ns

see figure 2
see figure 4

ELECTRICAL CHARACTERISTICS

 V_{CC} = +5V, T_{amb} = +25°C, Reset to V_{CC} (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
ICC	Supply Current (no load, High and Low States) $T_{amb} = +25$ °C $T_{min.} \le T_{amb} \le T_{max.}$		110	250 250	μA
V _{CL}	Control Voltage Level $T_{amb} = +25$ °C $T_{min.} \le T_{amb} \le T_{max.}$	2.9 2.8	3.3	3.8 3.9	V
V _{dis}	Discharge Stauration Voltage ($I_{dis} = 10$ mA) $T_{amb} = +25$ °C $T_{min.} \le T_{amb} \le T_{max.}$		0.2	0.3 0.35	V
V _{OL}	Low Level Output Voltage ($I_{sink} = 8mA$) $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		0.3	0.6 0.8	V
V _{OH}	High Level Output Voltage (I _{source} = -2mA) T_{amb} = +25°C $T_{min.} \le T_{amb} \le T_{max.}$	4.4 4.4	4.6		V
V _{trig}	Trigger Voltage T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}	1.36 1.26	1.67	1.96 2.06	V
I _{trig}	Trigger Current		10		pА
I _{TH}	Threshold Current		10		pА
V _{reset}	Reset Voltage T _{amb} = +25°C T _{min.} ≤ T _{amb} ≤ T _{max.}	0.4 0.3	1.1	1.5 2.0	V
I _{reset}	Reset Current		10		pА
I _{dis}	Discharge Pin Leakage Current		1	100	nA

DYNAMIC

Symbol	Parameter	Min.	Тур.	Max.	Unit
	Timing Accuracy (Monostable) - note ¹⁾ R = $10k\Omega$, C = 0.1μ F		2		%
	Timing Shift with Supply Voltage Variations (Monostable $R = 10k\Omega$, $C = 0.1\mu$ F,V _{CC} = +5V ±1V - see note 1		0.38		%/V
	Timing Shift with Temperature - see note 1 $T_{min.} \le T_{amb} \le T_{max}.5$		75		ppm/°C
f _{max}	Maximum Astable Frequency - note ²⁾ $R_A = 470\Omega$, $R_B = 200\Omega$, $C = 200pF$		2.7		MHz
	Astable Frequency Accuracy - see note 2 $R_A = R_B = 1k\Omega$ to 100k Ω , C = 0.1µF		3		%
	Timing Shift with Supply Voltage Variations (Astable mode) - see note 2 $R_A = R_B = 10k\Omega$, C = 0.1µF, V _{CC} = +5 to +12V		0.1		%/V
tr	Output Rise Time ₍ C _{load} = 10pF)		25		ns
tf	Output Fall Time ₍ C _{load} = 10pF)		20	-	ns
tpd	Trigger Propagation Delay)		100		ns
trpw	Minimum Reset Pulse Width (V _{trig} = +5V)		350		ns

see figure 2
see figure 4

TYPICAL CHARACTERISTICS

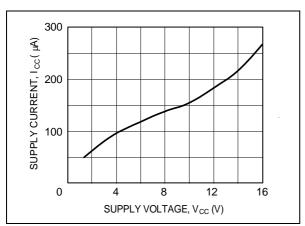


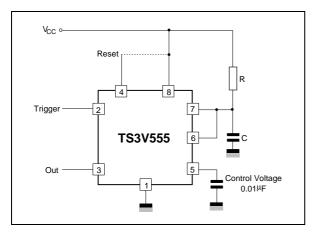
Figure 1 : Supply Current (each timer) versus Supply Voltage

APPLICATION INFORMATION

MONOSTABLE OPERATION

In the monostable mode, the timer functions as a one-shot. Referring to figure 2 the external capacitor is initially held discharged by a transistor inside the timer.

Figure 2 :



The circuit triggers on a negative-going input signal when the level reaches $1/3 V_{CC}$. Once triggered,the circuit remains in this state until the set time has elapsed,even if it is triggered again dur-

ing this interval. The duration of the output HIGH state is given by t = 1.1 R x C.

Notice that since the charge rate and the threshold level of the comparator are both directly proportional to supply voltage, the timing interval is independent of supply. Applying a negative pulse simultaneously to the Reset terminal (pin 4) and the Trigger terminal (pin 2) during the timing cycle discharges the external capacitor and causes the cycle to start over. The timing cycle now starts on the positive edge of the reset pulse. During the time the reset pulse is applied, the output is driven to its LOW state.

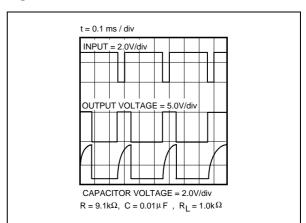
When a negative trigger pulse is applied to pin 2, the flip-flop is set, releasing the short circuit across the external capacitor and driving the output HIGH. The voltage across the capacitor increases exponentially with the time constant $\tau = R \times C$.

When the voltage across the capacitor equals 2/3 V_{CC}, the comparator resets the flip-flop which then discharges the capacitor rapidly and drives the output to its LOW state.

Figure 3 shows the actual waveforms generated in this mode of operation.

When Reset is not used, it should be tied high to avoid any possible or false triggering.







ASTABLE OPERATION

When the circuit is connected as shown in figure 4 (pin 2 and 6 connected) it triggers itself and free runs as a multivibrator. The external capacitor charges through R_A and R_B and discharges through R_B only. Thus the duty cycle may be precisely set by the ratio of these two resistors.

In the astable mode of operation, C charges and discharges between 1/3 V_{CC} and 2/3 V_{CC}. As in the triggered mode, the charge and discharge times and therefore frequency, are independent of the supply voltage.

Figure 4 :

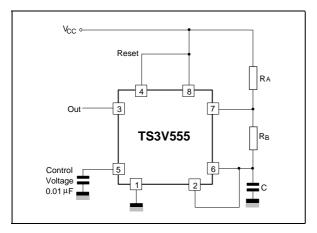


Figure 5 shows actual waveforms generated in this mode of operation.

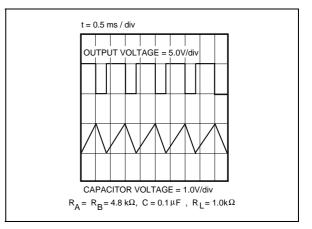
The charge time (output HIGH) is given by : $t1 = 0.693 (R_A + R_B) C$ and the discharge time (output LOW) by : $t2 = 0.693 (R_B) C$ Thus the total period T is given by : $T = t1 + t2 = 0.693 (R^A + 2R_B) C$ The frequency of oscillation is then :

$$f = \frac{1}{T} = \frac{1.44}{(RA + 2RB)C}$$

The duty cycle is given by :

$$\mathsf{D} = \frac{RB}{RA + 2RB}$$

Figure 5 :

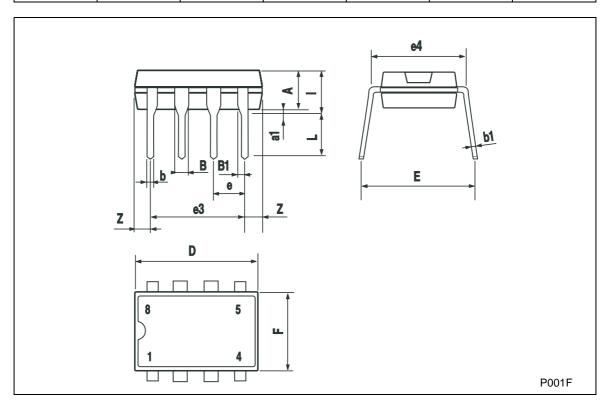


<u>\</u>

PACKAGE MECHANICAL DATA

57

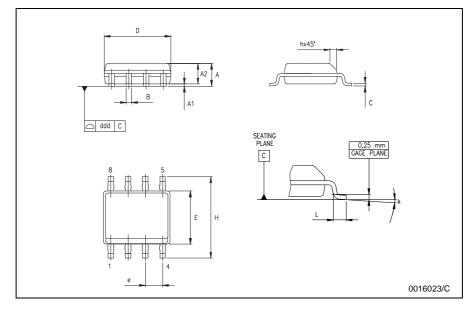
Plastic DIP-8 MECHANICAL DATA							
		mm.			inch		
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А		3.3			0.130		
a1	0.7			0.028			
В	1.39		1.65	0.055		0.065	
B1	0.91		1.04	0.036		0.041	
b		0.5			0.020		
b1	0.38		0.5	0.015		0.020	
D			9.8			0.386	
Е		8.8			0.346		
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			7.1			0.280	
I			4.8			0.189	
L		3.3			0.130		
Z	0.44		1.6	0.017		0.063	



7/8

PACKAGE MECHANICAL DATA

	SO-8 MECHANICAL DATA							
5.14		mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
А	1.35		1.75	0.053		0.069		
A1	0.10		0.25	0.04		0.010		
A2	1.10		1.65	0.043		0.065		
В	0.33		0.51	0.013		0.020		
С	0.19		0.25	0.007		0.010		
D	4.80		5.00	0.189		0.197		
Е	3.80		4.00	0.150		0.157		
е		1.27			0.050			
Н	5.80		6.20	0.228		0.244		
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
k		•	8° (r	nax.)	•	•		
ddd	1		0.1			0.04		



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics All other names are the property of their respective owners.

© 2003 STMicroelectronics - All Rights Reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Belgium - Brazil - Canada - China - Czech Repubic - Finland - France - Germany Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain Sweden - Switzerland - United Kingdom - United States http://www.st.com